

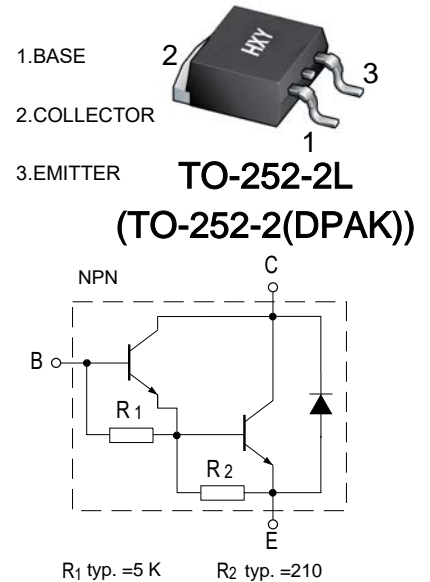


Features

- High DC Current Gain
- Electrically Similar to Popular TIP122
- Built-in a Damper Diode at E-C

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MJD122	TO-252-2L (TO-252-2(DPAK))	MJD122	2500



Maxmim Ratings (Ta=25 unless otherwise noted)

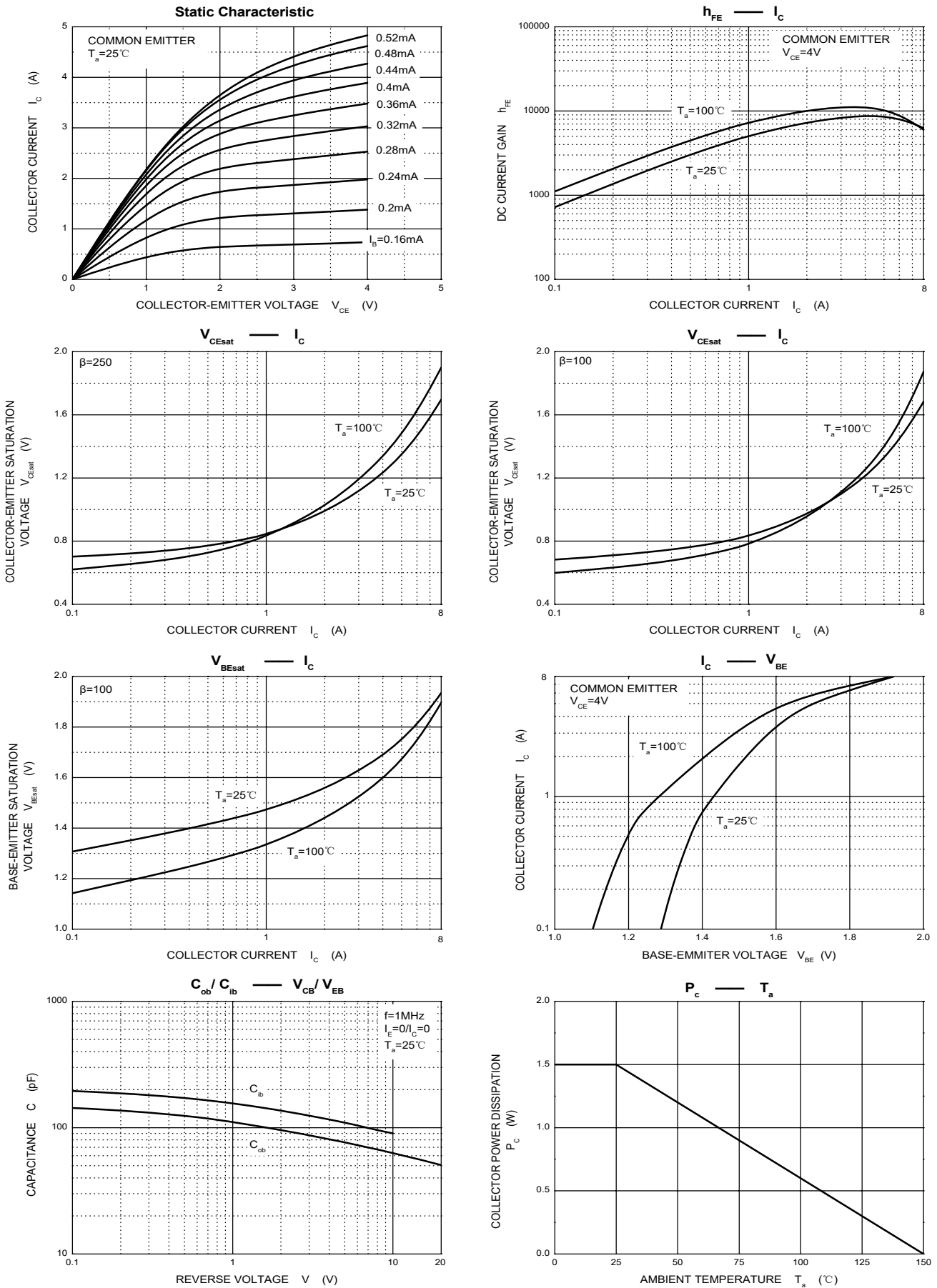
Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	100	V
V_{CEO}	Collector-Emitter Voltage	100	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	8	A
P_C	Collector Power Dissipation	1.5	W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55-150	°C

Electrcal Charcteristics (Ta=25 unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=1mA, I_E=0$	100			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=30mA, I_B=0$	100			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=3mA, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=100V, I_E=0$			10	μA
Collector-emitter cut-off current	I_{CEO}	$V_{CE}=50V, I_E=0$			10	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5V, I_C=0$			2	mA
DC current gain	$h_{FE(2)}$	$V_{CE}=4V, I_C=4A$	1000		12000	
	$h_{FE(3)}$	$V_{CE}=4V, I_C=8A$	100			
Collector-emitter saturation voltage	$V_{CE(sat)1}$	$I_C=4A, I_B=16mA$			2	V
	$V_{CE(sat)2}$	$I_C=8A, I_B=80mA$			4	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=8A, I_B=80mA$			4.5	V
Base-emitter voltage	V_{BE}	$V_{CE}=4V, I_C=4A$			2.8	V
Collector output capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=0.1MHz$			200	pF

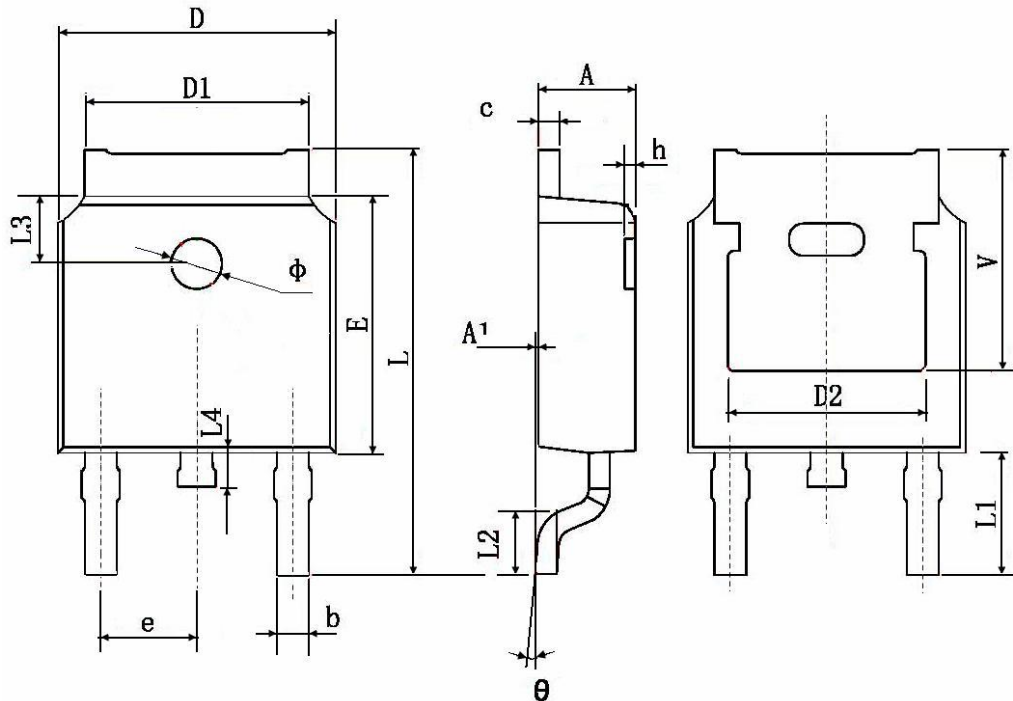


Typical Characteristics





TO-252-2L(TO-252-2(DPAK)) Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	0.483 TYP.		0.190 TYP.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067
L3	1.600 TYP.		0.063 TYP.	
L4	0.600	1.000	0.024	0.039
phi	1.100	1.300	0.043	0.051
theta	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 TYP.		0.211 TYP.	



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